

**75A, 1200V Hyperfast Diode**

The RHRG75120 is a hyperfast diode with soft recovery characteristics ( $t_{rr} < 85ns$ ). It has half the recovery time of ultrafast diodes and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of high frequency switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery characteristic minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA49042.

**Ordering Information**

PART NUMBER	PACKAGE	BRAND
RHRG75120	TO-247	RHRG75120

NOTE: When ordering, use the entire part number.

**Symbol**



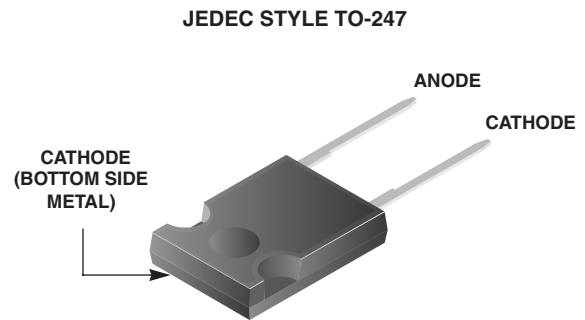
**Features**

- Hyperfast with Soft Recovery . . . . . <85ns
- Operating Temperature . . . . . 175°C
- Reverse Voltage . . . . . 1200V
- Avalanche Energy Rated
- Planar Construction

**Applications**

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

**Packaging**



**Absolute Maximum Ratings**  $T_C = 25^\circ C$

	RHRG75120	UNITS
Peak Repetitive Reverse Voltage . . . . . $V_{RRM}$	1200	V
Working Peak Reverse Voltage . . . . . $V_{RWM}$	1200	V
DC Blocking Voltage . . . . . $V_R$	1200	V
Average Rectified Forward Current . . . . . $I_{F(AV)}$ ( $T_C = 42^\circ C$ )	75	A
Repetitive Peak Surge Current . . . . . $I_{FRM}$ (Square Wave, 20kHz)	150	A
Nonrepetitive Peak Surge Current . . . . . $I_{FSM}$ (Halfwave, 1 Phase, 60Hz)	500	A
Maximum Power Dissipation . . . . . $P_D$	190	W
Avalanche Energy (See Figures 7 and 8) . . . . . $E_{AVL}$	50	mJ
Operating and Storage Temperature . . . . . $T_{STG}, T_J$	-65 to 175	°C

**Electrical Specifications**  $T_C = 25^\circ\text{C}$ , Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
$V_F$	$I_F = 75\text{A}$	-	-	3.2	V
	$I_F = 75\text{A}, T_C = 150^\circ\text{C}$	-	-	2.6	V
$I_R$	$V_R = 1200\text{V}$	-	-	250	$\mu\text{A}$
	$V_R = 1200\text{V}, T_C = 150^\circ\text{C}$	-	-	2	mA
$t_{rr}$	$I_F = 1\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	-	85	ns
	$I_F = 75\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	-	100	ns
$t_a$	$I_F = 75\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	60	-	ns
$t_b$	$I_F = 75\text{A}, dI_F/dt = 100\text{A}/\mu\text{s}$	-	25	-	ns
$R_{\theta JC}$		-	-	0.8	$^\circ\text{C}/\text{W}$

**DEFINITIONS**

$V_F$  = Instantaneous forward voltage ( $p_w = 300\mu\text{s}$ ,  $D = 2\%$ ).

$I_R$  = Instantaneous reverse current.

$t_{rr}$  = Reverse recovery time (See Figure 6), summation of  $t_a + t_b$ .

$t_a$  = Time to reach peak reverse current (See Figure 6).

$t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 6).

$R_{\theta JC}$  = Thermal resistance junction to case.

$p_w$  = Pulse width.

$D$  = Duty cycle.

**Typical Performance Curves**

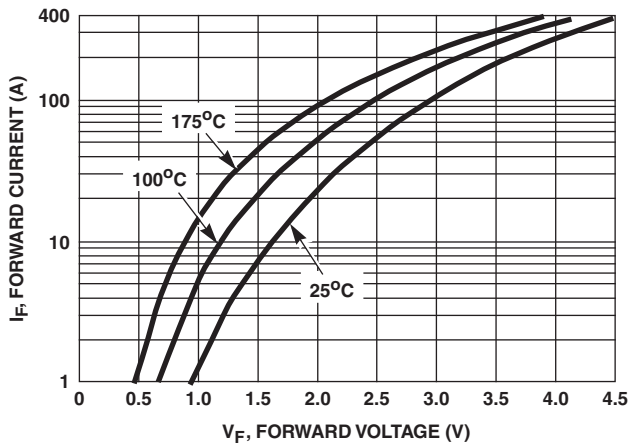


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

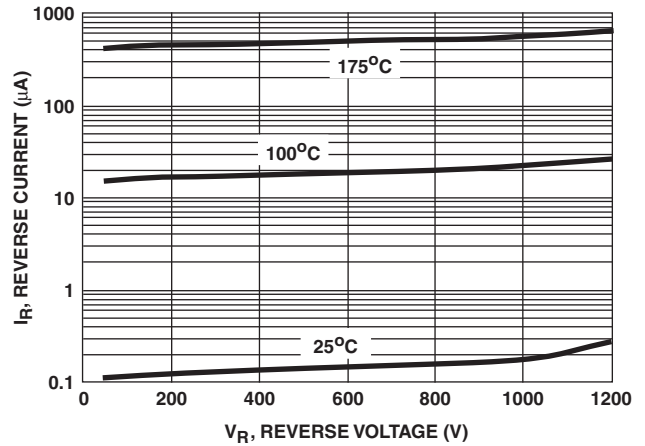


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

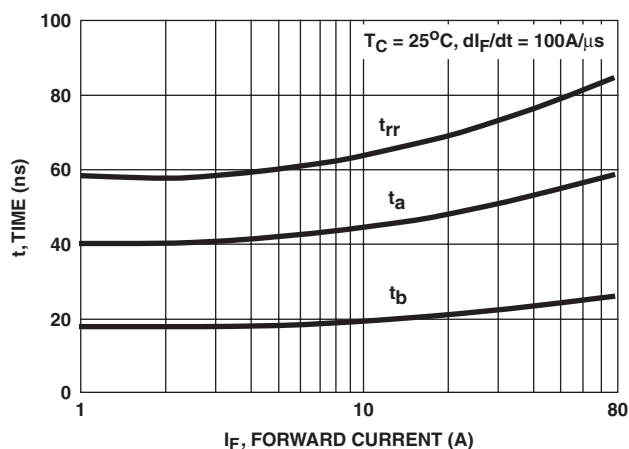


FIGURE 3.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

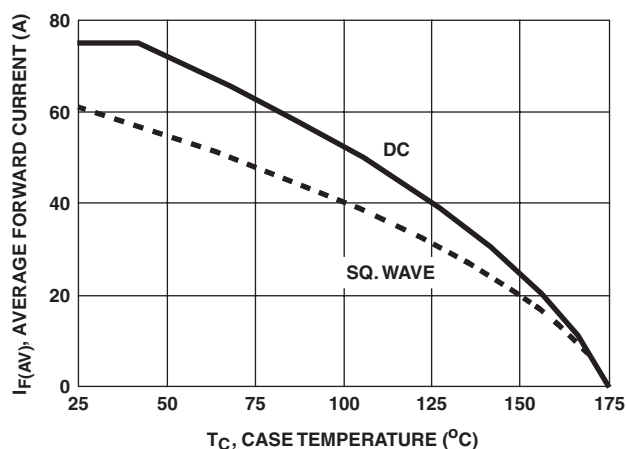


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

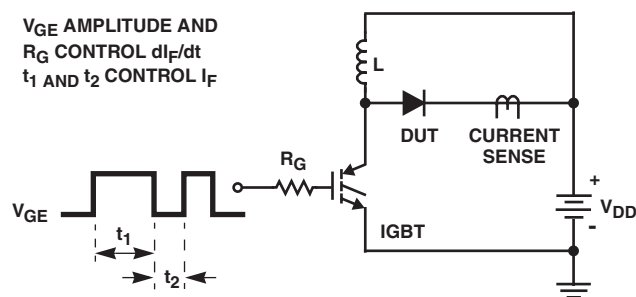


FIGURE 5.  $t_{rr}$  TEST CIRCUIT

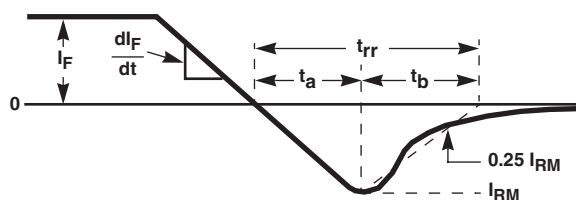


FIGURE 6.  $t_{rr}$  WAVEFORMS AND DEFINITIONS

$I_{MAX} = 1.6A$   
 $L = 40mH$   
 $R < 0.1\Omega$   
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$   
 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

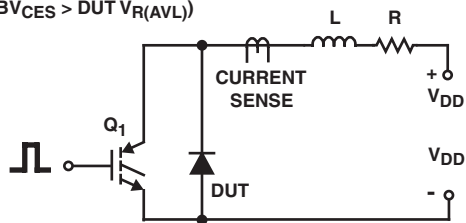


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

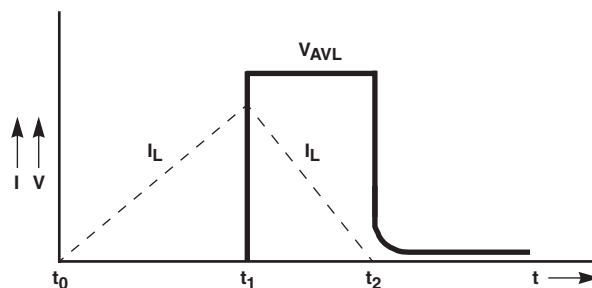





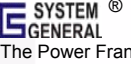


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



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